

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	26372	SOI (silicon near on near insulator)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 15:45
L3	12099	high near speed near3 (area region)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 15:46
L8	723	(mosfet misfet mos) same (fully near2 depleted)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 15:48
L9	2	2 and 3 and 8	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 15:49
L10	623	2 and 8	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 15:49
L11	535	10 and (@ad<"20020902" @rlad<"20020902")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/23 15:49